



CHENMKO ENTERPRISE CO.,LTD

Halogens free devices

SURFACE MOUNT SWITCHING DIODE

VOLTAGE 350 Volts CURRENT 225 mAmpere

CHBD3004BRMGP

APPLICATION

- * Ultra high speed switching

FEATURE

- * Small surface mounting type. (SC-74/SOT-457)
- * High speed. ($T_{RR}=50$ nSec Typ.)
- * Suitable for high packing density.
- * Maximum total power dissipation is 350mW.
- * Peak forward current is 625mA.
- * High voltage capability.

CONSTRUCTION

- * Silicon epitaxial planar

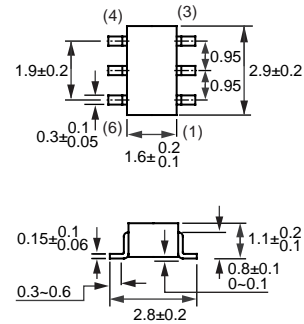
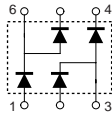
MARKING

- * D6P



SC-74/SOT-457

CIRCUIT



Dimensions in millimeters

SC-74/SOT-457

MAXIMUM RATINGS (At $T_A = 25^\circ\text{C}$ unless otherwise noted)

RATINGS		SYMBOL	CHBD3004BRMGP	UNITS
Maximum Recurrent Peak Reverse Voltage		V_{RRM}	350	Volts
Maximum RMS Voltage		V_{RMS}	300	Volts
Maximum DC Blocking Voltage		V_{DC}	212	Volts
Maximum Average Forward Rectified Current		I_O	225	mAmps
Peak Forward Surge Current	@ $T_P = 1\mu\text{Sec}$	I_{FSM}	4.0	Amps
	@ $T_P = 1\text{Sec}$		1.0	
Typical Junction Capacitance between Terminal (Note 1)		C_J	5.0	pF
Maximum Reverse Recovery Time (Note 2)		T_{RR}	50	nSec
Typical Thermal Resistance		$R_{\theta JA}$	357	$^\circ\text{C/W}$
Operation and Storage Temperature Range		T_J, T_{STG}	-65 to +150	$^\circ\text{C}$

ELECTRICAL CHARACTERISTICS (At $T_A = 25^\circ\text{C}$ unless otherwise noted)

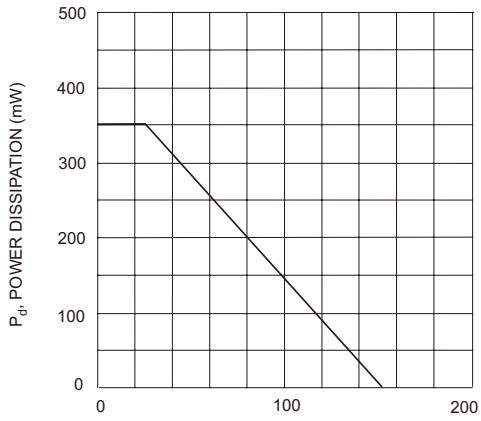
CHARACTERISTICS		SYMBOL	CHBD3004BRMGP	UNITS
Reverse Breakdown Voltage at $I_R = 150\mu\text{A}$		BV_R	350 Min.	Volts
Maximum Instantaneous Forward Voltage at $I_F = 100\text{mA}$		V_F	1.0	Volts
Maximum Average Reverse Current at $V_R = 240\text{V}$	@ $T_A = 25^\circ\text{C}$	I_R	100	nAmps
	@ $T_A = 150^\circ\text{C}$		100	uAmps

- NOTES : 1. Measured at 1.0 MHz and applied reverse voltage of 0 volts.
 2. Measured at applied forward current of 30mA ,reverse current of 30mA , $R_L=100 \Omega$ and recovery to $I_{RR}=3\text{mA}$.
 3. ESD sensitive product handling required.

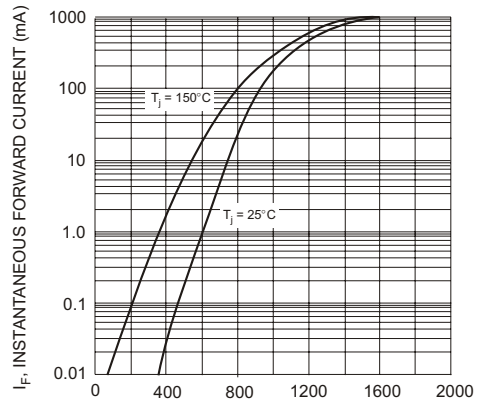
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RATING CHARACTERISTIC CURVES (CHBD3004BRMGP)

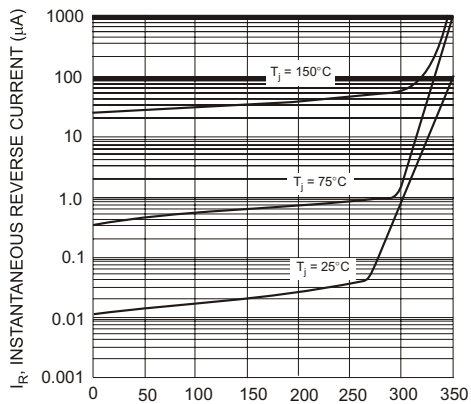
Typical Electrical Characteristics



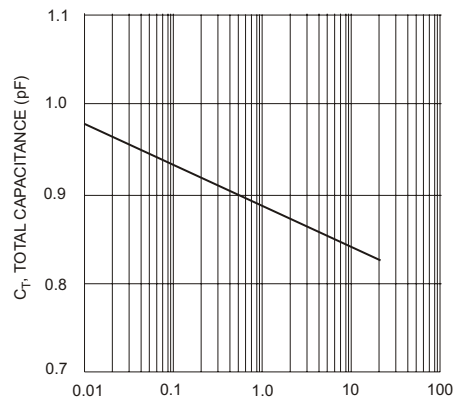
T_A , AMBIENT TEMPERATURE, (°C)
Fig. 1 Power Derating Curve, total package



V_F , INSTANTANEOUS FORWARD VOLTAGE (mV)
Fig. 2 Typical Forward Characteristics, per element



V_R , INSTANTANEOUS REVERSE VOLTAGE (V)
Fig. 3 Typical Reverse Characteristics, per element



V_R , REVERSE VOLTAGE (V)
Fig. 4 Typical Total Capacitance vs. Reverse Voltage, per element